

BQ27Z561 Impedance Track™ Battery Gas Gauge Solution for 1-Series Cell Li-Ion Battery Packs

1 Features

- Supports high-side and low-side current sense resistors: down to 1mΩ
- SHA-256 authentication responder for increased battery pack security
- Two independent ADCs
 - Support for simultaneous current and voltage sampling
 - High-accuracy coulomb counter with input offset error: < 1μV (typical)
- Low-voltage operation: 2V
- Supports pack-side gauging
- Wide-range current applications: 1mA to > 5A
- Active high or low interrupt pin
- Reduced power modes (typical battery pack operating range conditions)
 - Typical SLEEP mode: < 11μA
 - Typical DEEP SLEEP mode: < 9μA
 - Typical OFF mode: < 1.9μA
- Internal and external temperature sense functions
- 400kHz I²C bus communications interface for high-speed programming and data access
- HDQ one-wire for communication with host
- Compact 12-pin DSBGA package (YPH)

2 Applications

- [Smart phones](#)
- [Digital still and video cameras](#)
- [Tablet computing](#)
- [Portable and wearable health devices and portable audio devices](#)

3 Description

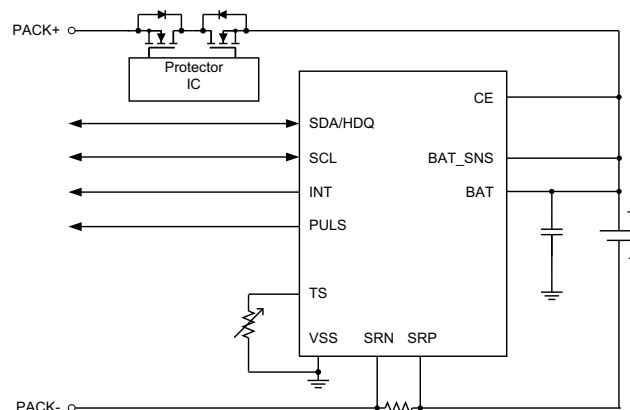
The Texas Instruments BQ27Z561 Impedance Track™ gas gauge solution is a highly integrated, accurate, 1-series cell gas gauge with a flash programmable custom reduced instruction-set CPU (RISC) and SHA-256 authentication for Li-ion and Li-polymer battery packs. The 1-series cell capability includes parallel cells for increased capacity.

The BQ27Z561 gas gauge communicates using I²C-compatible and HDQ one-wire interfaces and includes several key features that help facilitate accurate gas gauging applications. Integrated temperature sense functions (internal and external options) enable system and battery temperature measurements. The integrated SHA-256 functionality helps enable secure identification between systems and packs. The interrupt function facilitates the BQ27Z561 device to inform the system when a state-of-charge (SOC), voltage, or temperature fault occurs. The low-voltage operation enables the system to continue monitoring the battery, even in deeply discharged conditions. During low-activity situations, the device can be set to the low power coulomb counting (CC) mode, which allows the device to continue coulomb counting while significantly reducing operating current.

Package Information

PART NUMBER	PACKAGE ⁽¹⁾	PACKAGE SIZE ⁽²⁾
BQ27Z561	DSBGA (YPH, 12)	1.69mm × 2.07mm

- (1) For all available packages, see the orderable addendum at the end of the data sheet.
- (2) The package size (length × width) is a nominal value and includes pins, where applicable.



Simplified Schematic



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4 Pin Configuration and Functions

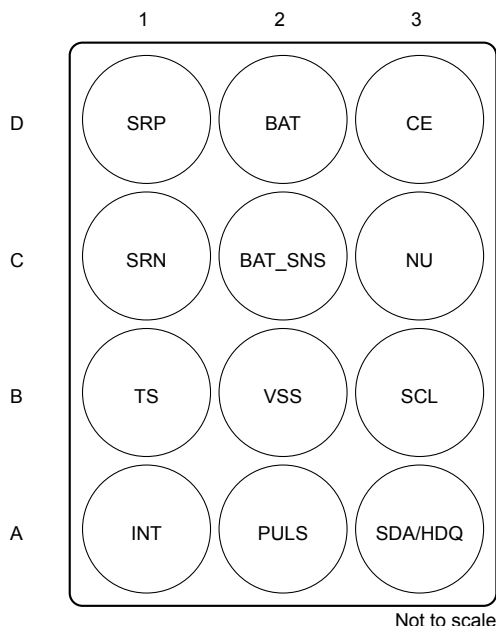


Table 4-1. Pin Functions

NUMBER	NAME	TYPE ⁽¹⁾	DESCRIPTION
D2	BAT	P	Battery voltage measurement input. Kelvin battery sense connection to BAT_SNS. Connect a capacitor (1μF) between BAT and VSS. Place the capacitor close to the gauge.
D3	CE	I	Active high chip enable
C2	BAT_SNS	AI	Battery sense
A1	INT	O	Interrupt for voltage, temperature, and state of charge (programmable active high or low)
A2	PULS	O	Programmable pulse width with active high or low option
B1	TS	AI	Temperature input for ADC
C3	NU	NU	Makes no external connection
B3	SCL	I/O	Serial clock for I ² C interface; requires external pull up when used. It can be left floating if unused.
A3	SDA/HDQ	I/O	Serial data for I ² C interface and one-wire interface for HDQ (selectable); requires external pull up when used. It can be left floating if unused.
D1	SRP	I	Analog input pin connected to the internal coulomb counter peripheral for integrating a small voltage between SRP (positive side) and SRN
C1	SRN	I	Analog input pin connected to the internal coulomb counter peripheral for integrating a small voltage between SRP (positive side) and SRN.
B2	VSS	P	Device ground

(1) P = Power Connection, O = Digital Output, AI = Analog Input, I = Digital Input, I/O = Digital Input/Output, NU = Not Used

5 Specifications

5.1 Absolute Maximum Ratings

Over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
Input Voltage	BAT	−0.3	6	V
	INT, PULS, CE	−0.3	6	V
	SRP, SRN, BAT_SNS	−0.3	$V_{BAT} + 0.3$	V
	TS	−0.3	2.1	V
	SCL, SDA/HDQ	−0.3	6	V
Operating ambient temperature, T_A		−40	85	°C
Operating junction temperature, T_J		−40	125	°C
Storage temperature, T_{stg}		−65	150	°C

- (1) Operation outside the *Absolute Maximum Ratings* may cause permanent device damage. *Absolute Maximum Ratings* do not imply functional operation of the device at these or any other conditions beyond those listed under *Recommended Operating Conditions*. If used outside the *Recommended Operating Conditions* but within the *Absolute Maximum Ratings*, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.

5.2 ESD Ratings

		VALUE	UNIT
$V_{(ESD)}$ Electrostatic discharge	Human-body model (HBM) on all pins, per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±1500	V
	Charged-device model (CDM) on all pins, per JEDEC specification JESD22-C101 ⁽²⁾	±500	

- (1) JEDEC document JEP155 states that 500V HBM enables safe manufacturing with a standard ESD control process.
 (2) JEDEC document JEP157 states that 250V CDM enables safe manufacturing with a standard ESD control process.

5.3 Recommended Operating Conditions

Unless otherwise noted, characteristics noted under conditions of $T_A = -40^{\circ}\text{C}$ to 85°C

			MIN	NOM	MAX	UNIT
V_{BAT}	Supply voltage	No operating restrictions	2.0		5.5	V
C_{BAT}	External capacitor from BAT to VSS		1			μF
V_{TS}	Temperature sense		0		1.8	V
$V_{PULS}, V_{INT}, V_{CE}$	Input and output pins		0		V_{BAT}	V
$V_{SCL}, V_{SDA/HDQ}$	Communication pins		0		V_{BAT}	V

5.4 Thermal Information

Over-operating free-air temperature range (unless otherwise noted)

THERMAL METRIC ⁽¹⁾		BQ27Z561	UNIT
		DSBGA (YPH)	
		(12 PINS)	
R _{θJA}	Junction-to-ambient thermal resistance	64.1	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	59.8	
R _{θJB}	Junction-to-board thermal resistance	52.7	
Ψ _{JT}	Junction-to-top characterization parameter	0.3	
Ψ _{JB}	Junction-to-board characterization parameter	28.3	
R _{θJC(bot)}	Junction-to-case (bottom) thermal resistance	2.4	

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics application note](#).

5.5 Supply Current

Unless otherwise noted, characteristics noted under conditions of T_A = –40°C to 85°C

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
I _{NORMAL}	Standard operating Conditions		60		μA
I _{SLEEP}	Sense resistor current below SLEEP mode threshold		11		μA
I _{DEEPSLEEP}	Sense resistor current below DEEP SLEEP mode threshold		9		μA
I _{OFF}	CE = V _{IL}		0.5		μA

5.6 Internal 1.8V LDO (REG18)

Unless otherwise noted, characteristics noted under conditions of T_A = –40°C to 85°C

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V _{REG18}	Regulator output voltage	1.6	1.8	2.0	V
V _{PORth}	POR threshold	Rising Threshold	1.45	1.7	V
V _{PORhy}	POR hysteresis		0.1		V

5.7 I/O (PULS, INT)

Unless otherwise noted, characteristics noted under conditions of T_A = –40°C to 85°C

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V _{IH}	High-level input voltage	V _{REG18} = 1.8V	1.15		V
V _{IL}	Low-level input voltage low	V _{REG18} = 1.8V		0.50	V
V _{OL}	Output voltage low	V _{REG18} = 1.8V, I _{OL} = 1mA		0.4	V
C _I	Input capacitance		5		pF
I _{Ikg}	Input leakage current			1	μA

5.8 Chip Enable (CE)

Unless otherwise noted, characteristics noted under conditions of T_A = –40°C to 85°C

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V _{IH}	High-level input voltage ⁽¹⁾	V _{REG18} = 1.8V	0.75 × V _{BAT}		V
V _{IL}	Low-level input voltage low ⁽¹⁾	V _{REG18} = 1.8V	0.25 × V _{BAT}		V

(1) Specified by design

5.9 Internal Temperature Sensor

Unless otherwise noted, characteristics noted under conditions of $T_A = -40^{\circ}\text{C}$ to 85°C

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
$V_{(\text{TEMP})}$ Internal Temperature sensor voltage drift	V_{TEMPP}	1.65	1.73	1.8	mV/ $^{\circ}\text{C}$
	$V_{\text{TEMPP}} - V_{\text{TEMPN}}$ (assured by design)	0.17	0.18	0.19	

5.10 NTC Thermistor Measurement Support

Unless otherwise noted, characteristics noted under conditions of $T_A = -40^{\circ}\text{C}$ to 85°C

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
$R_{\text{NTRC(PU)}}$ Internal Pullup Resistance		14.4	18	21.6	k Ω
$R_{\text{NTC(DRIFT)}}$ Resistance drift over temperature		-250	-120	0	PPM/ $^{\circ}\text{C}$

5.11 Coulomb Counter (CC)

Unless otherwise noted, characteristics noted under conditions of $T_A = -40^{\circ}\text{C}$ to 85°C

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
$V_{(\text{CC_IN})}$ Differential input voltage range		-0.1		0.1	V
$t_{(\text{CC_CONV})}$ Conversion time	Single conversion		1000		ms
Effective Resolution	1LSB		3.8		μV
Integral nonlinearity	16-bit, Best fit over input voltage range	-22.3	5.2	+22.3	LSB
Differential nonlinearity	16-bit, No missing codes		1.5		LSB
Offset error	16-bit Post-Calibration	-2.6	1.3	+2.6	LSB
Offset error drift	15-bit + sign, Post Calibration		0.04	0.07	LSB/ $^{\circ}\text{C}$
Gain Error	15-bit + sign, Over input voltage range	-492	131	+492	LSB
Gain Error drift	15-bit + sign, Over input voltage range		4.3	9.8	LSB/ $^{\circ}\text{C}$
Effective input resistance		7			M Ω

5.12 Analog Digital Converter (ADC)

Unless otherwise noted, characteristics noted under conditions of $T_A = -40^{\circ}\text{C}$ to 85°C

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
$V_{\text{ADC_TS_GPIO}}$ Input voltage range	$V_{\text{FS}} = V_{\text{REF2}}$	-0.2		1.0	V
	$V_{\text{FS}} = V_{\text{REG18}} \times 2$	-0.2		1.44	V
$V_{\text{BAT_MODE}}$ Battery Input Voltage		-0.2		5.5	V
Integral nonlinearity	16-bit, Best fit, -0.1V to $0.8 \times V_{\text{REF2}}$	-8.4		+8.4	LSB
Differential nonlinearity	16-bit, No missing codes		1.5		LSB
Offset error	16-bit Post-Calibration ⁽¹⁾ , $V_{\text{FS}} = V_{\text{REF2}}$	-4.2	1.8	+4.2	LSB
Offset error drift	16-bit Post-Calibration ⁽¹⁾ , $V_{\text{FS}} = V_{\text{REF2}}$		0.02	0.1	LSB/ $^{\circ}\text{C}$
Gain Error	16-bit, -0.1 to $0.8 \times V_{\text{FS}}$	-492	131	+492	LSB
Gain Error drift	16-bit, -0.1 to $0.8 \times V_{\text{FS}}$		2	4.5	LSB/ $^{\circ}\text{C}$
Effective input resistance		8			M Ω
$t_{(\text{ADC_CONV})}$ Conversion time			11.7		ms
Effective resolution		14	15		bits

(1) Factory calibration.

5.13 Internal Oscillator Specifications

Unless otherwise noted, characteristics noted under conditions of $T_A = -40^{\circ}\text{C}$ to 85°C

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
High Frequency Oscillator (HFO)					
f _{HFO}	Operating frequency		16.78		MHz
f _{HFO}	HFO frequency drift	TA = −20°C to 70°C	−2.5%	2.5%	
		TA = −40°C to 85°C	−3.5	3.5	
t _{HFOSTART}	HFO Start-up time	TA = −40°C to 85°C, oscillator frequency within ± 3% of nominal frequency or a power-on reset			4 ms
Low Frequency Oscillator (LFO)					
f _{LFO}	Operating frequency		65.536		kHz
f _{LFO(ERR)}	Frequency error	TA = −40°C to 85°C	−2.5%	+2.5%	

5.14 Voltage Reference1 (REF1)

Unless otherwise noted, characteristics noted under conditions of $T_A = -40^{\circ}\text{C}$ to 85°C

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{REF1}	Internal Reference Voltage ⁽¹⁾	1.195	1.21	1.227	V
$V_{\text{REF1_DRIFT}}$	Internal Reference Voltage Drift	$T_A = -40^{\circ}\text{C}$ to 85°C			-80 +80 PPM/C

(1) Used for CC and LDO

5.15 Voltage Reference2 (REF2)

Unless otherwise noted, characteristics noted under conditions of $T_A = -40^{\circ}\text{C}$ to 85°C

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{REF2}	Internal Reference Voltage ⁽¹⁾	1.2	1.21	1.22	V
$V_{\text{REF2_DRIFT}}$	Internal Reference Voltage Drift	$T_A = -40^{\circ}\text{C}$ to 85°C			-20 20 PPM/ $^{\circ}\text{C}$

(1) Used for ADC

5.16 Flash Memory

Unless otherwise noted, characteristics noted under conditions of $T_A = -40^{\circ}\text{C}$ to 85°C

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Data retention		10	100		Years
Flash programming write cycles	Data Flash	20000			Cycles
	Instruction Flash	1000			Cycles
$t_{\text{(ROWPROG)}}$	Row programming time			40	μs
$t_{\text{(MASSERASE)}}$	Mass-erase time	$T_A = -40^{\circ}\text{C}$ to 85°C			40 ms
$t_{\text{(PAGEERASE)}}$	Page-erase time	$T_A = -40^{\circ}\text{C}$ to 85°C			40 ms
$I_{\text{FLASHREAD}}$	Flash Read Current	$T_A = -40^{\circ}\text{C}$ to 85°C			1 mA
$I_{\text{FLASHWRTIE}}$	Flash Write Current	$T_A = -40^{\circ}\text{C}$ to 85°C			5 mA
$I_{\text{FLASHERASE}}$	Flash Erase Current	$T_A = -40^{\circ}\text{C}$ to 85°C			15 mA

5.17 I²C I/O

Unless otherwise noted, characteristics noted under conditions of $T_A = -40^{\circ}\text{C}$ to 85°C

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{IH}	High-level input voltage	SCL, SDA/HDQ, $V_{REG18} = 1.8\text{V}$	1.26			V
V_{IL}	Low-level input voltage low	$V_{REG18} = 1.8\text{V}$			0.54	V
V_{OL}	Low-level output voltage	$I_{OL} = 1\text{mA}$, $V_{REG18} = 1.8\text{V}$			0.36	V
C_I	Input capacitance				10	pF
I_{Ikg}	Input leakage current			1		μA

5.18 I²C Timing — 100kHz

PARAMETER		TEST CONDITIONS	MIN	NOM	MAX	UNIT
f_{SCL}	Clock Operating Frequency	SCL duty cycle = 50%			100	kHz
$t_{HD:STA}$	START Condition Hold Time		4.0			μs
t_{LOW}	Low period of the SCL Clock		4.7			μs
t_{HIGH}	High period of the SCL Clock		4.0			μs
$t_{SU:STA}$	Setup repeated START		4.7			μs
$t_{HD:DAT}$	Data hold time (SDA input)		0			ns
$t_{SU:DAT}$	Data setup time (SDA input)		250			ns
t_r	Clock Rise Time	10% to 90%			1000	ns
t_f	Clock Fall Time	90% to 10%			300	ns
$t_{SU:STO}$	Setup time STOP Condition		4.0			μs
t_{BUF}	Bus free time STOP to START		4.7			μs

5.19 I²C Timing — 400kHz

PARAMETER		TEST CONDITIONS	MIN	NOM	MAX	UNIT
f_{SCL}	Clock Operating Frequency	SCL duty cycle = 50%			400	kHz
$t_{HD:STA}$	START Condition Hold Time		0.6			μs
t_{LOW}	Low period of the SCL Clock		1.3			μs
t_{HIGH}	High period of the SCL Clock		600			ns
$t_{SU:STA}$	Setup repeated START		600			ns
$t_{HD:DAT}$	Data hold time (SDA input)		0			ns
$t_{SU:DAT}$	Data setup time (SDA input)		100			ns
t_r	Clock Rise Time	10% to 90%			300	ns
t_f	Clock Fall Time	90% to 10%			300	ns
$t_{SU:STO}$	Setup time STOP Condition		0.6			μs
t_{BUF}	Bus free time STOP to START		1.3			μs

5.20 HDQ Timing

PARAMETER		TEST CONDITIONS	MIN	NOM	MAX	UNIT
t_B	Break Time		190			μs
t_{BR}	Break Recovery Time		40			μs
t_{HW1}	Host Write 1 Time	Host drives HDQ	0.5		50	μs
t_{HW0}	Host Write 0 Time	Host drives HDQ	86		145	μs
t_{CYCH}	Cycle Time, Host to device	Device drives HDQ	190			μs

PARAMETER		TEST CONDITIONS	MIN	NOM	MAX	UNIT
t _{CYCD}	Cycle Time, device to Host	Device drives HDQ	190	205	250	μs
t _{DW1}	Device Write 1 Time	Device drives HDQ	32		50	μs
t _{DW0}	Device Write 0 Time	Device drives HDQ	80		145	μs
t _{RSPS}	Device Response Time	Device drives HDQ	190		950	μs
t _{TRND}	Host Turn Around Time	Host drives HDQ after device drives HDQ	250			μs
t _{RISE}	HDQ Line Rising Time to Logic 1				1.8	μs
t _{RST}	HDQ Reset	Host drives HDQ low before device reset	2.2			s

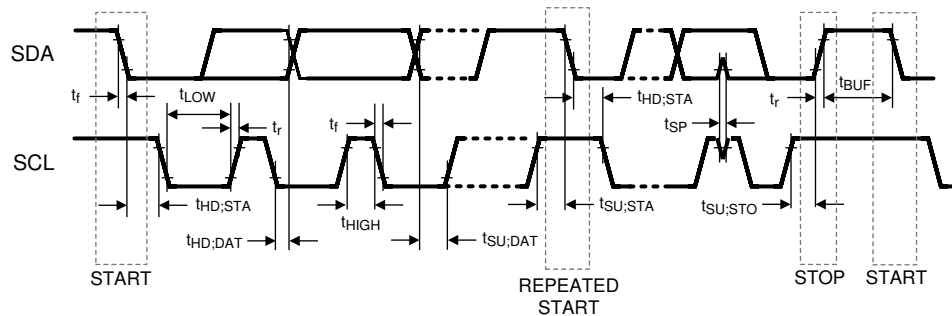
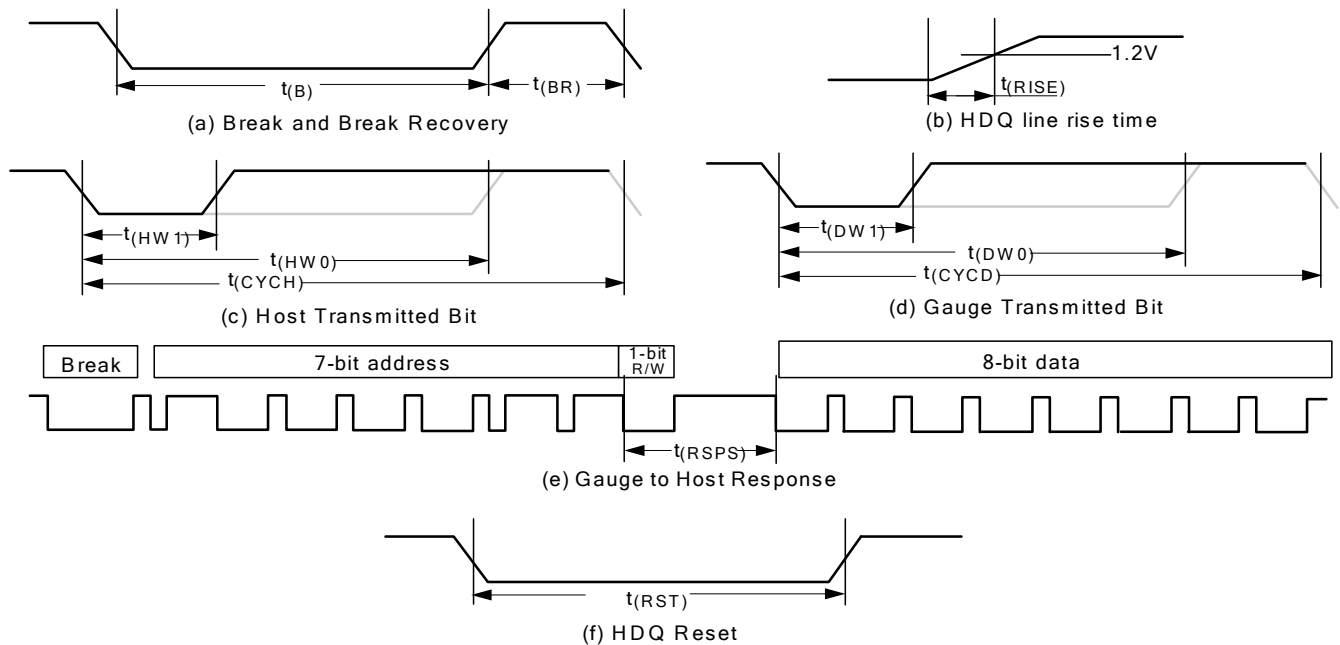


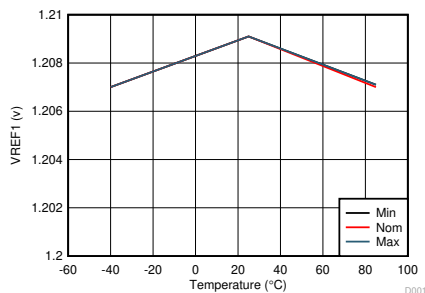
Figure 5-1. I²C Timing



- a. HDQ Breaking
- b. Rise time of HDQ line
- c. HDQ Host to fuel gauge communication
- d. Fuel gauge to Host communication
- e. Fuel gauge to Host response format
- f. HDQ Host to fuel gauge

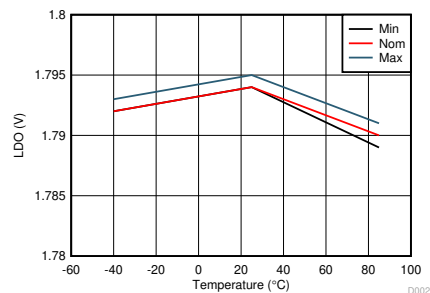
Figure 5-2. HDQ Timing

5.21 Typical Characteristics



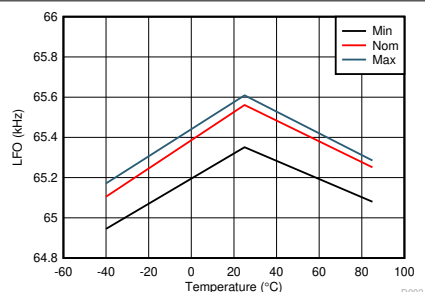
A. BAT Min = 2V BAT Nom = 3.6V BAT Max = 5V

Figure 5-3. REF1 Voltage Versus Battery and Temperature



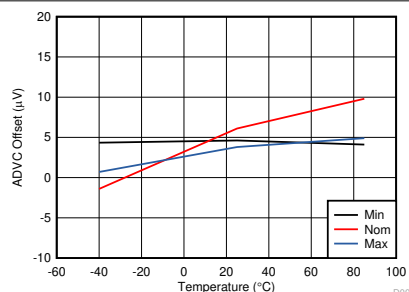
A. BAT Min = 2V BAT Nom = 3.6V BAT Max = 5V

Figure 5-4. LDO Voltage Versus Battery and Temperature



A. BAT Min = 2V BAT Nom = 3.6V BAT Max = 5V

Figure 5-5. LFO Frequency Versus Battery and Temperature



A. BAT Min = 2V BAT Nom = 3.6V BAT Max = 5V

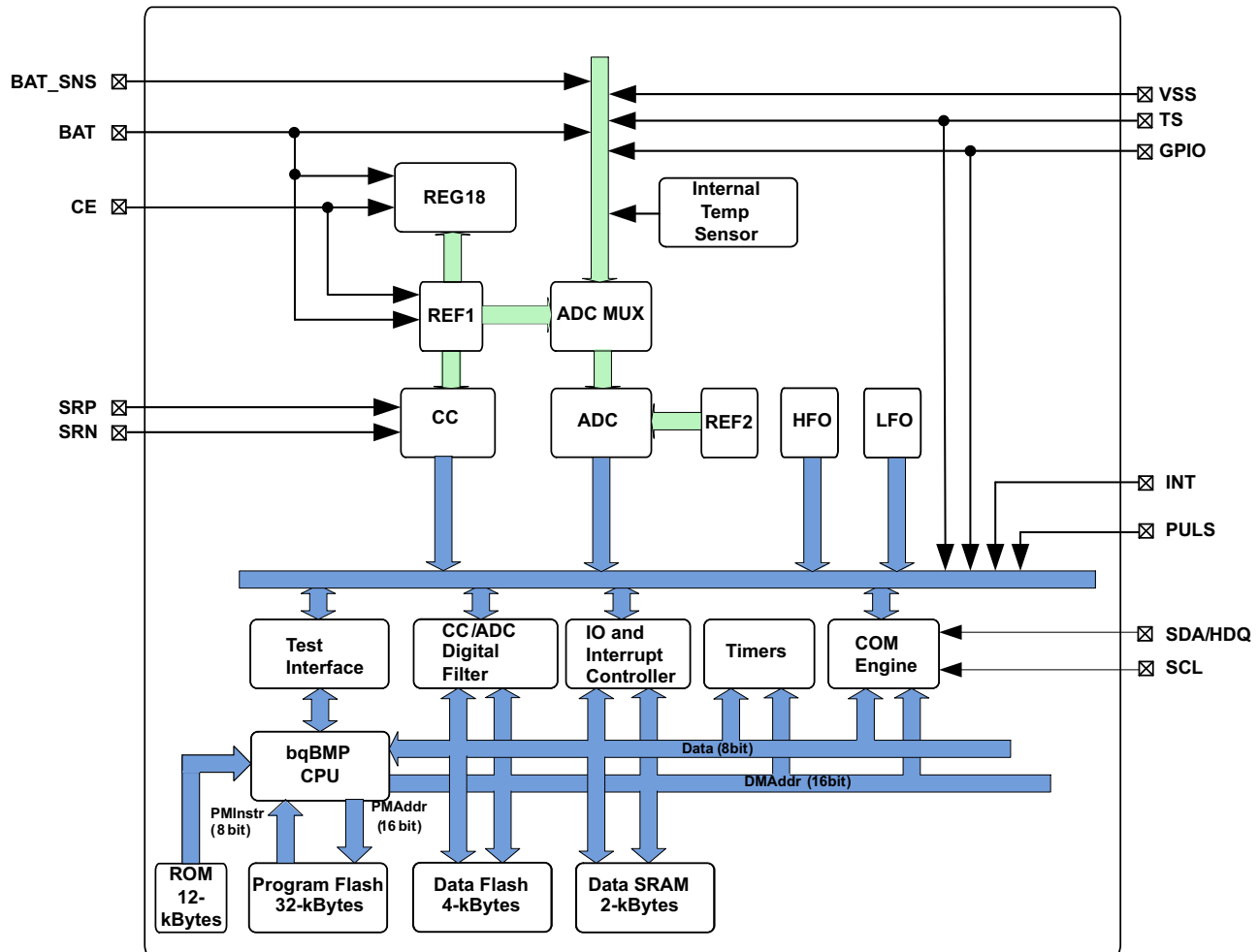
Figure 5-6. ADVC Offset Voltage Versus Battery and Temperature

6 Detailed Description

6.1 Overview

The BQ27Z561 gas gauge is a fully integrated battery manager that employs flash-based firmware to provide a complete solution for battery-stack architectures composed of 1-series cells. The BQ27Z561 device interfaces with a host system using a I²C or HDQ protocol. High-performance, integrated analog peripherals enable support for a sense resistor down to 1mΩ, and simultaneous current and voltage data conversion for instant power calculations. The following sections detail all of the major component blocks included as part of the BQ27Z561 device.

6.2 Functional Block Diagram



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6.3 Feature Description

6.3.1 BQ27Z561 Processor

The BQ27Z561 device uses a custom TI-proprietary processor design that features a Harvard architecture and operates at frequencies up to 4.2MHz. Using an adaptive, three-stage instruction pipeline, the BQ27Z561 processor supports variable instruction lengths of 8, 16, or 24 bits.

6.3.2 Battery Parameter Measurements

The BQ27Z561 device measures cell voltage and current simultaneously, and also measures temperature to calculate the information related to remaining capacity, full charge capacity, state-of-health, and other gauging parameters.

6.3.2.1 Coulomb Counter (CC)

The first ADC is an integrating analog-to-digital converter designed specifically for tracking charge and discharge activity, or coulomb counting, of a rechargeable battery. The first ADC features a single-channel differential input that converts the voltage difference across a sense resistor between the SRP and SRN terminals with a resolution of $3.74\mu\text{V}$.

6.3.2.2 CC Digital Filter

The CC digital filter generates a 16-bit conversion value from the delta-sigma CC front-end. The FIR filter uses the HFO clock output. New conversions are available every 1s.

6.3.2.3 ADC Multiplexer

The ADC multiplexer provides selectable connections to the external pins BAT, BAT_SNS, TS, the internal temperature sensor, internal reference voltages, internal 1.8V regulator, and VSS ground reference input. In addition, the multiplexer can independently enable the TS input connection to the internal thermistor biasing circuitry, and enables the user to short the multiplexer inputs for test and calibration purposes.

6.3.2.4 Analog-to-Digital Converter (ADC)

The second ADC is a 16-bit delta-sigma converter designed for general-purpose measurements. The ADC automatically scales the input voltage range during sampling based on channel selection. The converter resolution is a function of the full-scale range and number of bits, yielding a $38\mu\text{V}$ resolution.

6.3.2.5 Internal Temperature Sensor

An internal temperature sensor is available on the BQ27Z561 device to reduce the cost, power, and size of the external components necessary to measure temperature. The sensor is available for connection to the ADC using the multiplexer, and is designed to quickly determine pack temperature under a variety of operating conditions.

6.3.2.6 External Temperature Sensor Support

The TS input is enabled with an internal $18\text{k}\Omega$ (typical) linearization pull-up resistor to support the use of a $10\text{k}\Omega$ (25°C) NTC external thermistor, such as the Semitec™ 103AT-2. Connect the NTC thermistor between VSS and the individual TS pin. Take the analog measurement using the ADC through the ADC input multiplexer. If a different thermistor type is required, then changes to configurations can be required.

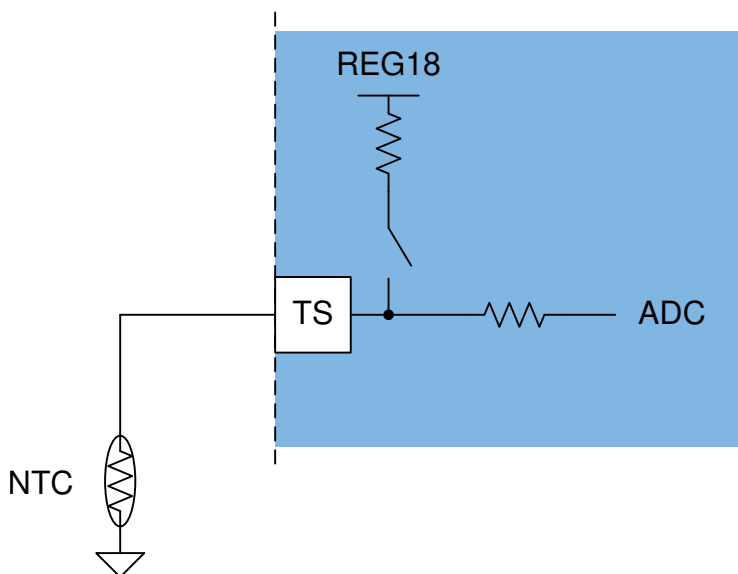


Figure 6-1. External Thermistor Biasing

6.3.3 Power Supply Control

The BQ27Z561 device uses the BAT pin as its power source. BAT powers the internal voltage sources that supply references for the device. BAT_SNS is a non-current carrying path and used at the Kelvin reference for BAT.

6.3.4 Bus Communication Interface

The BQ27Z561 device has an I²C bus communication interface. Alternatively, configure the BQ27Z561 to communicate through the HDQ pin (shared with SDA).

Note

Once the device switches to the HDQ protocol, the switch is not reversible.

6.3.5 Low Frequency Oscillator

The BQ27Z561 device includes a low frequency oscillator (LFO) running at 65.536kHz.

6.3.6 High Frequency Oscillator

The BQ27Z561 includes a high frequency oscillator (HFO) running at 16.78MHz. The HFO is frequency locked to the LFO output and scaled down to 8.388MHz with a 50% duty cycle.

6.3.7 1.8V Low Dropout Regulator

The BQ27Z561 device contains an integrated capacitor-less 1.8V LDO (REG18) that provides regulated supply voltage for the device CPU and internal digital logic.

6.3.8 Internal Voltage References

The BQ27Z561 device provides two internal voltage references. REF1 is used by REG18, oscillators, and CC. REF2 is used by the ADC.

6.3.9 Gas Gauging

This device uses the Impedance Track™ technology to measure and determine the available charge in battery cells. See the [Theory and Implementation of Impedance Track Battery Fuel-Gauging Algorithm application note](#) for further details.

6.3.10 Charge Control Features

This device supports charge control features, such as:

- Reports charging voltage and charging current based on the active temperature range—JEITA temperature ranges T1, T2, T3, T4, T5, and T6
- Provides more complex charging profiles, including sub-ranges within a standard temperature range
- Reports the appropriate charging current required for constant current charging, and the appropriate charging voltage needed for constant voltage charging to a smart charger, using the bus communication interface
- Selects the chemical state-of-charge of each battery cell using the Impedance Track method
- Reports charging faults and indicates charge status through charge and discharge alarms

6.3.11 Authentication

This device supports security with the following features, which can be enabled if desired:

- Authentication by the host using the SHA-256 method
- The gas gauge requires SHA-256 authentication before the device can be unsealed or allow full access.

6.4 Device Functional Modes

This device supports four modes, but the current consumption varies, based on firmware control of certain functions and modes of operation:

- **NORMAL mode:** In this mode, the device performs measurements, calculations, protections, and data updates every 250ms intervals. Between intervals, the device operates in a reduced power stage to minimize total average current consumption.
- **SLEEP mode:** In this mode, the device performs measurements, calculations, and data updates in adjustable time intervals. Between intervals, the device operates in a reduced power stage to minimize total average current consumption.
- **DEEP SLEEP mode:** In this mode, the current reduces slightly while current and voltage are still measured periodically, with a user-defined time between reads.
- **OFF mode:** The device is completely disabled by pulling CE low. CE disables the internal voltage rail. All non-volatile memory is unprotected.

6.4.1 Lifetime Logging Features

The device supports data logging of several key parameters for warranty and analysis:

- Maximum and minimum cell temperature
- Maximum current in CHARGE or DISCHARGE mode
- Maximum and minimum cell voltages

6.4.2 Configuration

The device supports accurate data measurements and data logging of several key parameters.

6.4.2.1 Coulomb Counting

The device uses an integrating delta-sigma analog-to-digital converter (ADC) for current measurement. The ADC measures charge and discharge flow of the battery by measuring the voltage across a very small external sense resistor. The integrating ADC measures a bipolar signal from a range of -100mV to 100mV , with a positive value when $V_{(\text{SRP})} - V_{(\text{SRN})}$, indicating charge current and a negative value indicating discharge current.

The system performs the current measurement by measuring the voltage drop across the external sense resistor, which can be as low as $1\text{m}\Omega$, and determines the cell's mode (CHARGE or DISCHARGE) based on the polarity of the differential voltage.

6.4.2.2 Cell Voltage Measurements

The BQ27Z561 gas gauge measures the cell voltage at 1s intervals using the ADC. The voltage measured value is internally scaled for the ADC and is calibrated to reduce any errors due to offsets. The data is also used to calculate the impedance of the cell for Impedance Track gas gauging.

6.4.2.3 Auto Calibration

The auto-calibration feature helps to cancel any voltage offset across the SRP and SRN pins for accurate measurement of the cell voltage, charge or discharge current, and thermistor temperature. The auto-calibration is performed when there is no communication activity for a minimum of 5s on the bus lines.

6.4.2.4 Temperature Measurements

This device has an internal sensor for on-die temperature measurements, and the ability to support an external temperature measurement using the external NTC on the TS pin. These two measurements are individually enabled and configured.

7 Applications and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

7.1 Application Information

The BQ27Z561 gas gauge can be used with a 1-series Li-ion or Li-polymer battery pack. To implement and design a comprehensive set of parameters for a specific battery pack, use the Battery Management Studio ([bqStudio](#)), a graphical user-interface tool installed on a PC during development. The firmware installed in the product has default values, which are summarized in the [BQ27Z561 Technical Reference Manual](#). Using the bqStudio tool, change the default values to cater to specific application requirements during development once the system parameters, such as enable and disable of certain features for operation, cell configuration, chemistry that best matches the cell used, and more, are known. The final flash image is extracted once configuration and testing are complete. Use the final flash image for mass production. The image is referred to as the *golden image*.

7.2 Typical Applications

The following is an example BQ27Z561 application schematic for a single-cell battery pack.

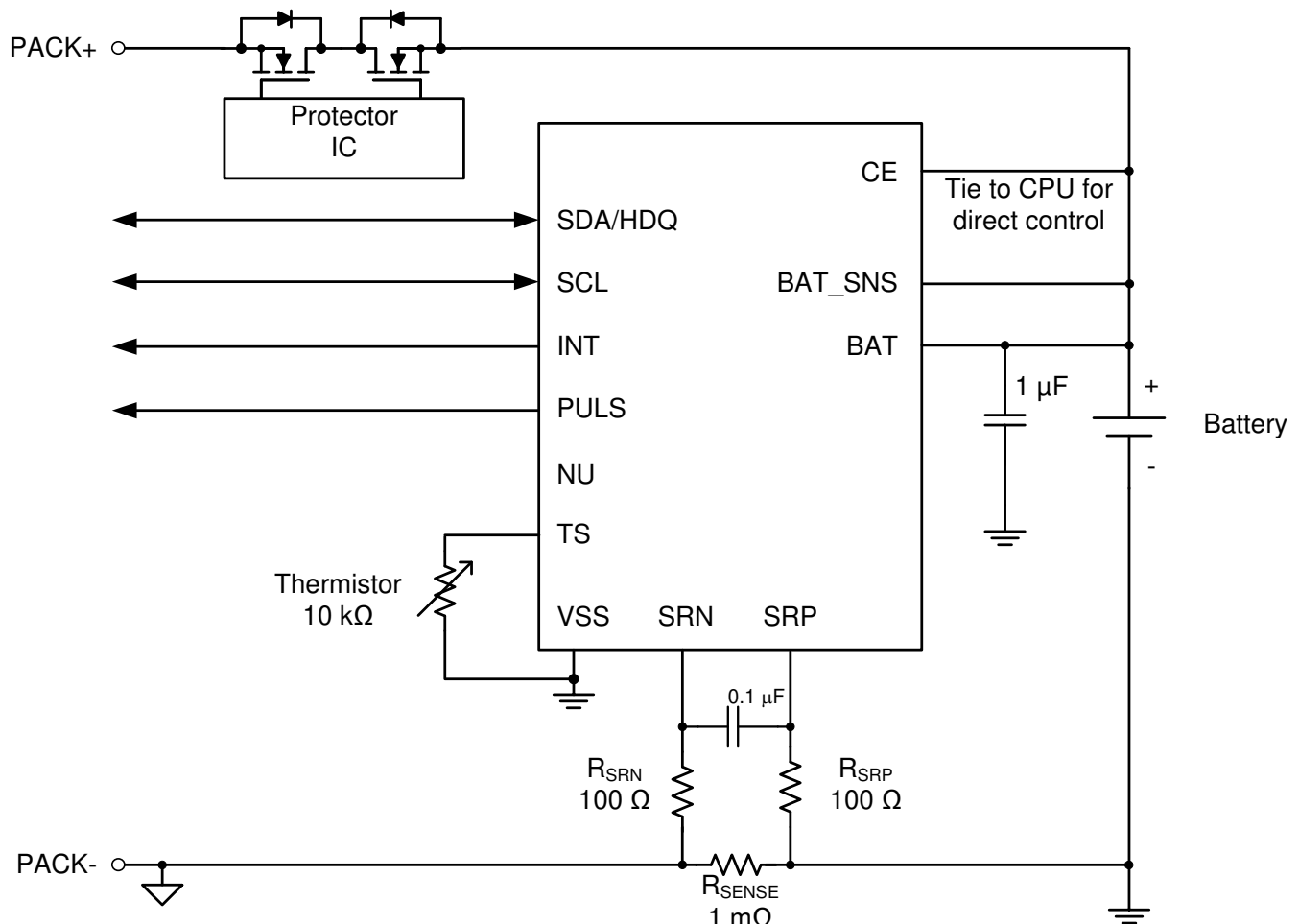


Figure 7-1. BQ27Z561 1-Series Cell Typical Implementation

7.2.1 Design Requirements (Default)

Design Parameter	Example
Cell Configuration	1s1p (1 series with 1 parallel)
Design Capacity	5300mAh
Device Chemistry	Li-ion
Design Voltage	4000mV
Cell Low Voltage	2500mV

7.2.2 Detailed Design Procedure

7.2.2.1 Changing Design Parameters

For the firmware settings needed for the design requirements, refer to the [BQ27Z561 Technical Reference Manual](#).

- To change design capacity, set the data flash value (in mAh) in the **Gas Gauging: Design: Design Capacity** register.
- To set device chemistry, go to the data flash **I²C Configuration: Data: Device Chemistry**. The bqStudio software automatically populates the correct chemistry identification. This selection is derived from using the bqCHEM feature in the tools and choosing the option that matches the device chemistry from the list.
- To set the design voltage, go to **Gas Gauging: Design: Design Voltage** register.
- To set the Cell **Low Voltage** or clear the Cell **Low Voltage**, use **Settings: Configuration: Init Voltage Low Set** or **Clear**. This is used to set the cell voltage level that will set (clear) the [VOLT_LO] bit in the **Interrupt Status** register.
- To enable the internal temperature and the external temperature sensors: Set **Settings: Configuration: Temperature Enable**: Bit 0 (TSInt) = 1 for the internal sensor; set Bit 1 (TS1) = 1 for the external sensor.

7.2.3 Calibration Process

The calibration of current, voltage, and temperature readings is accessible by writing 0xF081 or 0xF082 to **ManufacturerAccess()**. A detailed procedure is included in the [BQ27Z561 Technical Reference Manual](#) in the **Calibration** section. The description allows for calibration of cell voltage measurement offset, battery voltage, current calibration, coulomb counter offset, PCB offset, CC gain/capacity gain, and temperature measurement for both internal and external sensors.

7.2.4 Gauging Data Updates

When a battery pack enabled with the BQ27Z561 gas gauge is cycled, the value of **FullChargeCapacity()** updates several times, including the onset of charge or discharge, charge termination, temperature delta, resistance updates during discharge, and relaxation. [Figure 7-2](#) shows actual battery voltage, load current, and **FullChargeCapacity()** when some of those updates occur during a single application cycle.

Update points from the plot include:

- Charge termination at 7900s
- Relaxation at 9900s
- Resistance update at 11500s

7.2.4.1 Application Curve

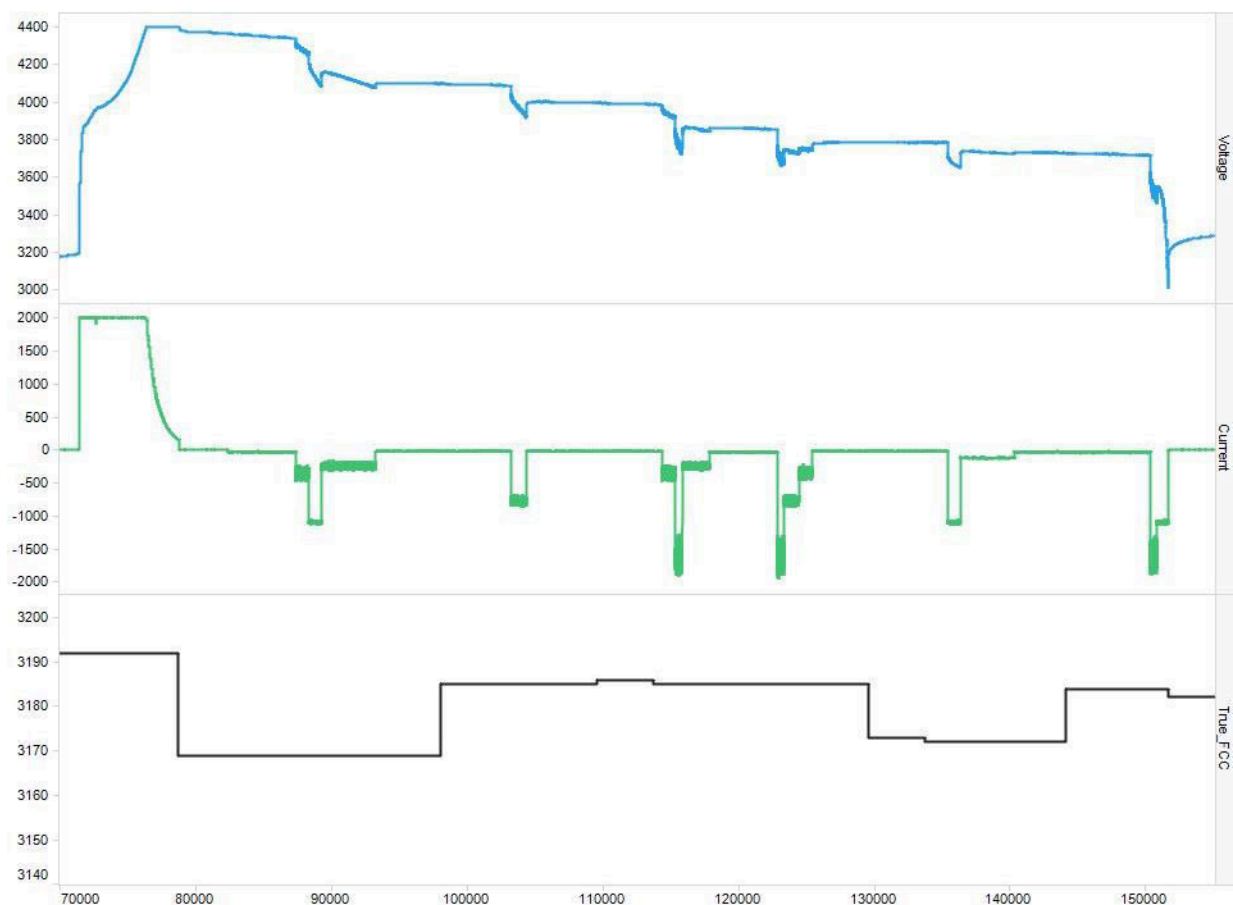


Figure 7-2. Full Charge Capacity Tracking (X-Axis Is Seconds)

7.3 Power Supply Requirements

The only power supply is the BAT pin, connects to the positive terminal of the battery. The input voltage for the BAT pin has a minimum of 2V and a maximum of 5V.

7.4 Layout

7.4.1 Layout Guidelines

- The quality of the Kelvin connections at the sense resistor is critical. Verify that the sense resistor has a temperature coefficient no greater than 50ppm to minimize current measurement drift with temperature. Choose the value of the sense resistor in correspondence with the available overcurrent and short-circuit ranges of the BQ27Z561 gas gauge. Select the smallest value possible to minimize the negative voltage generated on the BQ27Z561 VSS node during a short circuit. This pin has an absolute minimum of $-0.3V$. Use parallel resistors as long as good Kelvin sensing is established. The design of the device supports a $1m\Omega$ to $3m\Omega$ sense resistor.
- Directly tie the BAT_SNS to the positive connection of the battery. Confirm that the BAT_SNS shows not share a path with the BAT pin.
- In reference to the gas gauge circuit, differential low-pass filter and I²C communication require attention for component placement and layout.
- The BQ27Z561 gas gauge uses an integrating delta-sigma ADC for current measurements. Add a 100Ω resistor from the sense resistor to the SRP and SRN inputs of the device. Place a $0.1\mu F$ filter capacitor across the SRP and SRN inputs. If required for a circuit, add $0.1\mu F$ filter capacitors for additional noise filtering for each sense input pin to ground. Place all filter components as close as possible to the device.

Route the traces from the sense resistor in parallel to the filter circuit. Add a ground plane around the filter network to provide additional noise immunity.

- The BQ27Z561 has an internal LDO that is internally compensated and does not require an external decoupling capacitor.
- The I²C clock and data pins have integrated high-voltage ESD protection circuits; however, adding a Zener diode and series resistor provides more robust ESD performance. The I²C clock and data lines have an internal pull-down. When the gas gauge senses that both lines are low (such as during removal of the pack), the device performs auto-offset calibration and enters into SLEEP mode to conserve power.

7.4.2 Layout Example

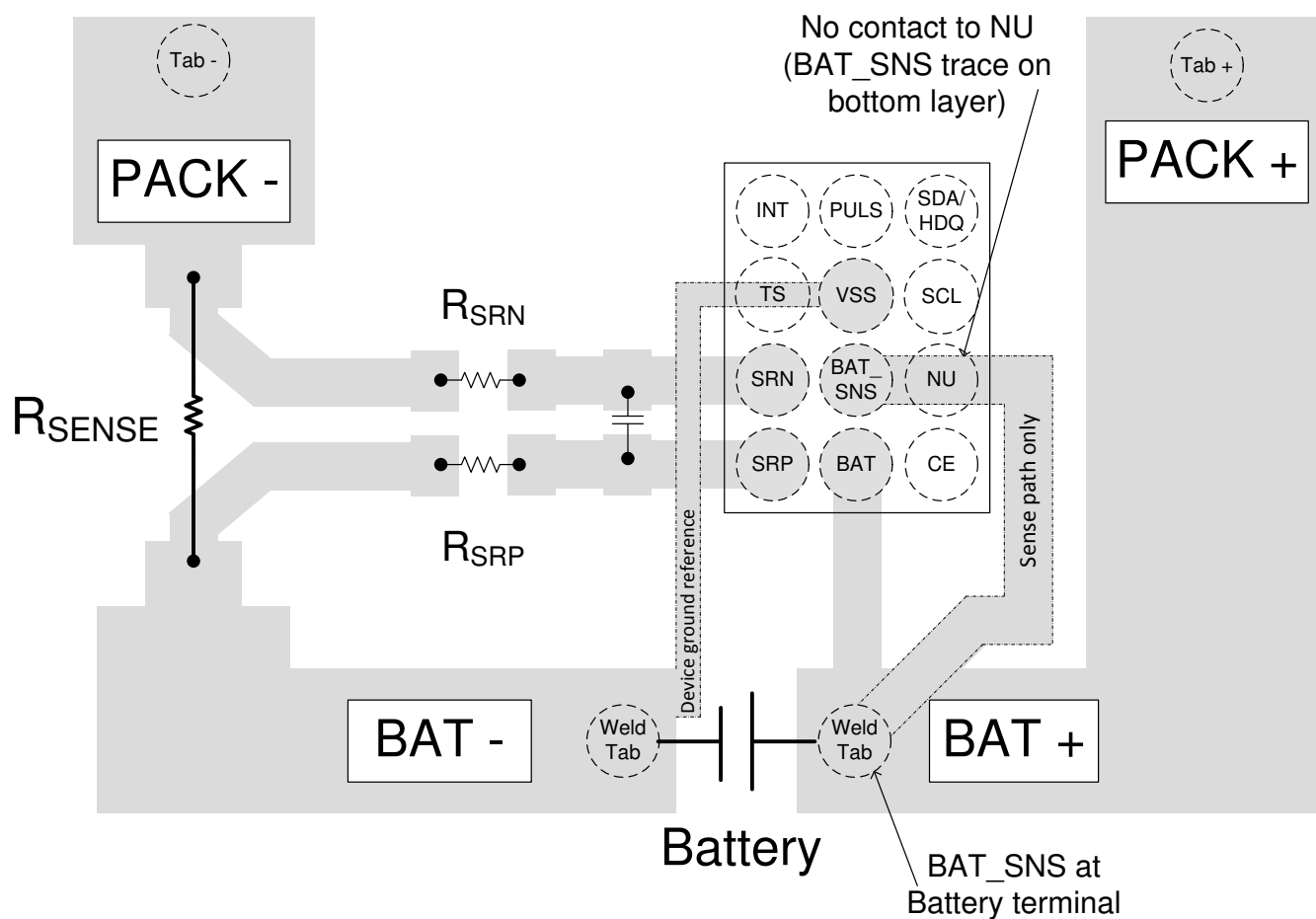


Figure 7-3. BQ27Z561 Key Trace Board Layout

8 Device and Documentation Support

8.1 Device Support

8.1.1 Third-Party Products Disclaimer

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8.2 Documentation Support

8.2.1 Related Documentation

- Texas Instruments, [BQ27Z561 Technical Reference Manual](#)
- Texas Instruments, [BQSTUDIO software](#)
- Texas Instruments, [Theory and Implementation of Impedance Track™ Battery Fuel-Gauging Algorithm in bq2750x Family application note](#)

8.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on **Alert me** to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

8.4 Support Resources

[TI E2E™ support forums](#) are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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8.5 Trademarks

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8.6 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

8.7 Glossary

[TI Glossary](#) This glossary lists and explains terms, acronyms, and definitions.

9 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision B (October 2022) to Revision C (September 2025)	Page
• Updated the numbering format for tables, figures, and cross-references throughout the document.....	1
• Removed the CE reference from I/O section.....	5
• Updated from: Input voltage range to: Differential input voltage range.....	6

Changes from Revision A (August 2019) to Revision B (October 2022)**Page**

- Changed body size in *Device Information* 1
- Added Chip Enable (CE) section which includes CE pin thresholds that are specified by design..... 5

10 Mechanical, Packaging, Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
BQ27Z561YPHR	Active	Production	DSBGA (YPH) 12	3000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 85	BQ27Z561
BQ27Z561YPHR.A	Active	Production	DSBGA (YPH) 12	3000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 85	BQ27Z561
BQ27Z561YPHR.B	Active	Production	DSBGA (YPH) 12	3000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 85	BQ27Z561
BQ27Z561YPHT	Active	Production	DSBGA (YPH) 12	250 SMALL T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 85	BQ27Z561
BQ27Z561YPHT.A	Active	Production	DSBGA (YPH) 12	250 SMALL T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 85	BQ27Z561
BQ27Z561YPHT.B	Active	Production	DSBGA (YPH) 12	250 SMALL T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 85	BQ27Z561

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

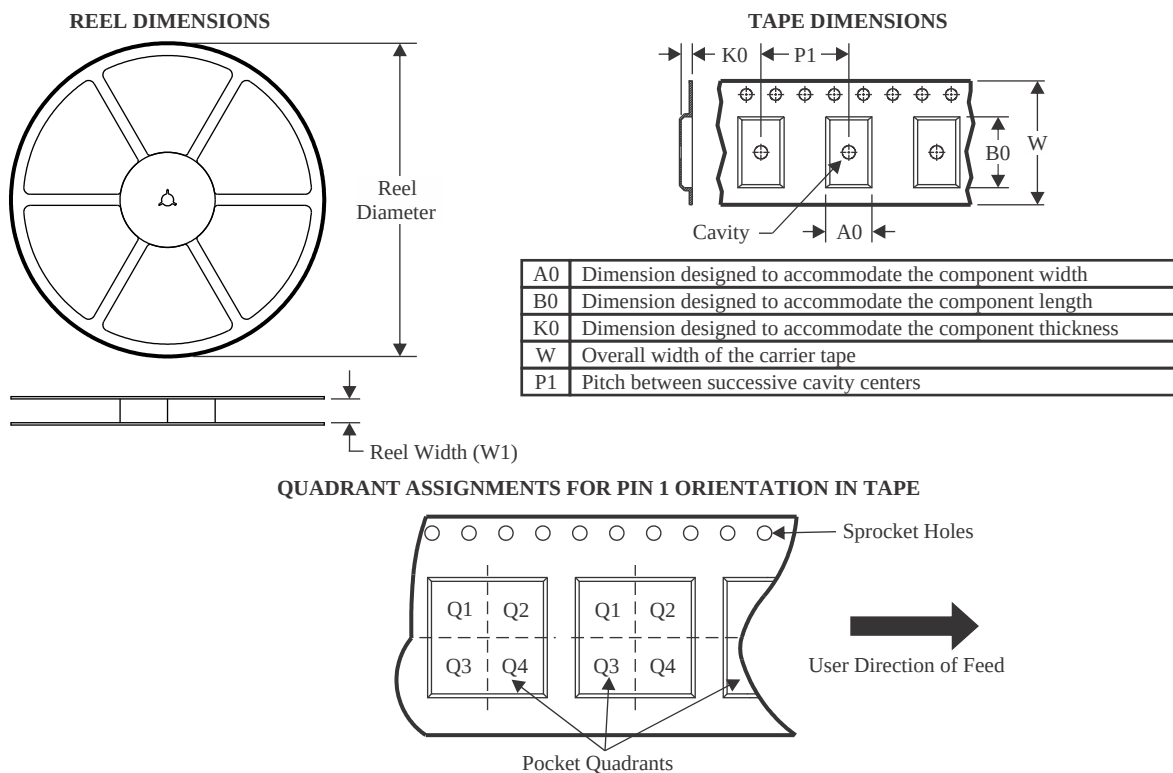
⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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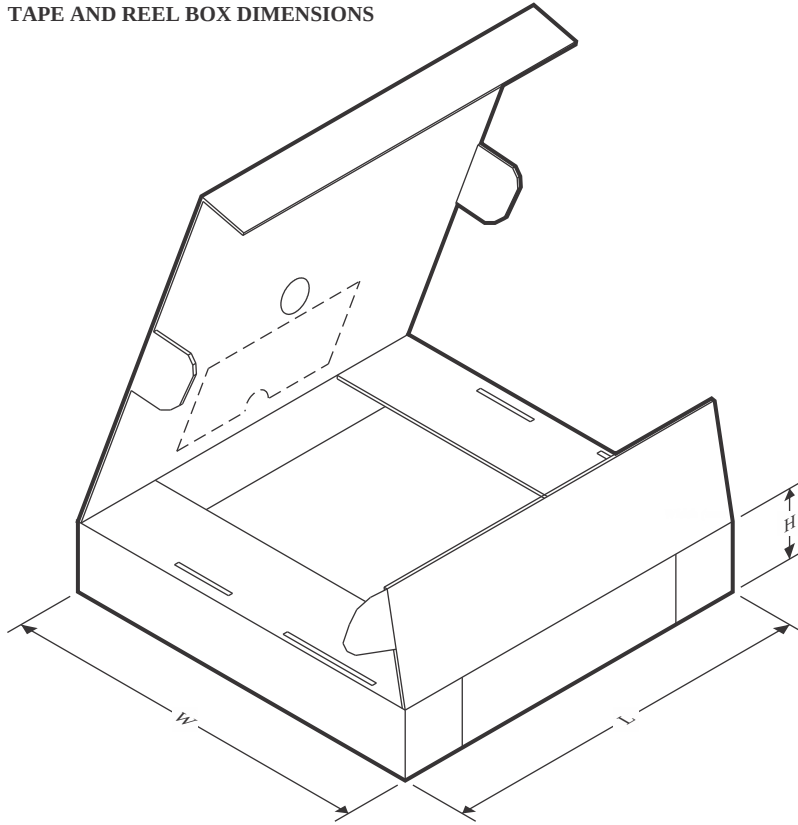
TAPE AND REEL INFORMATION



*All dimensions are nominal

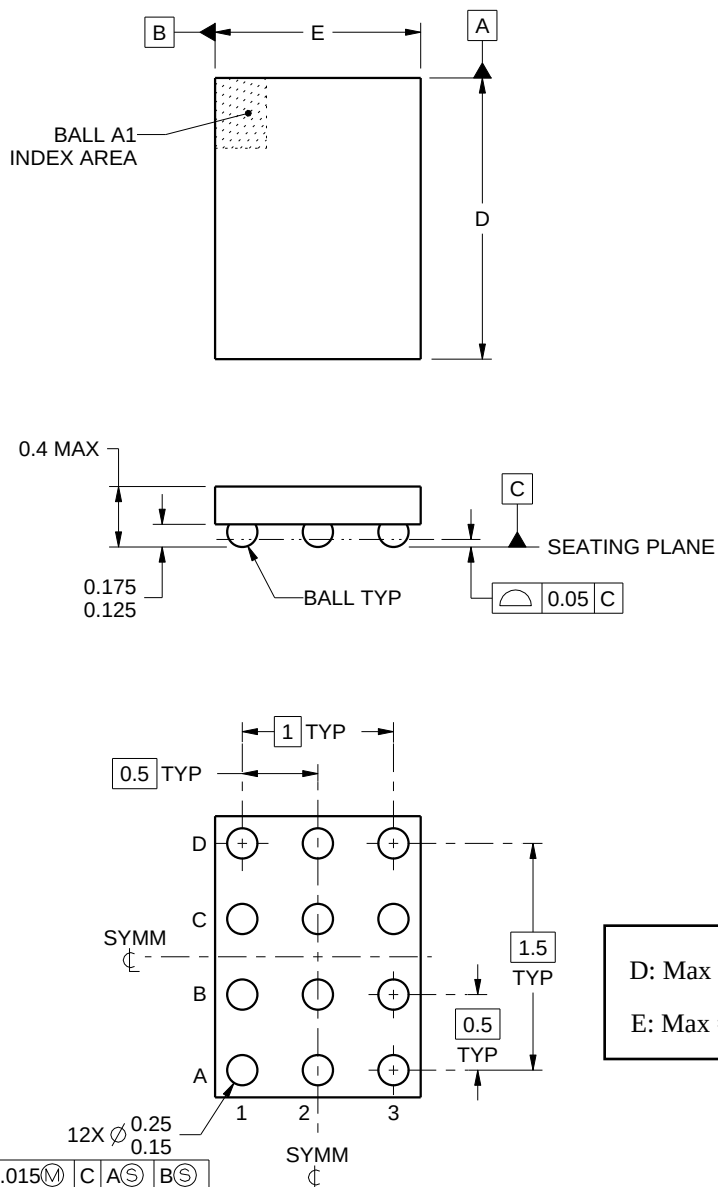
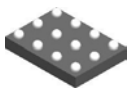
Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
BQ27Z561YPHR	DSBGA	YPH	12	3000	180.0	8.4	1.83	2.2	0.53	4.0	8.0	Q1
BQ27Z561YPHT	DSBGA	YPH	12	250	180.0	8.4	1.83	2.2	0.53	4.0	8.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
BQ27Z561YPHR	DSBGA	YPH	12	3000	182.0	182.0	20.0
BQ27Z561YPHT	DSBGA	YPH	12	250	182.0	182.0	20.0



4222640/A 12/2015

NOTES:

NanoFree Is a trademark of Texas Instruments.

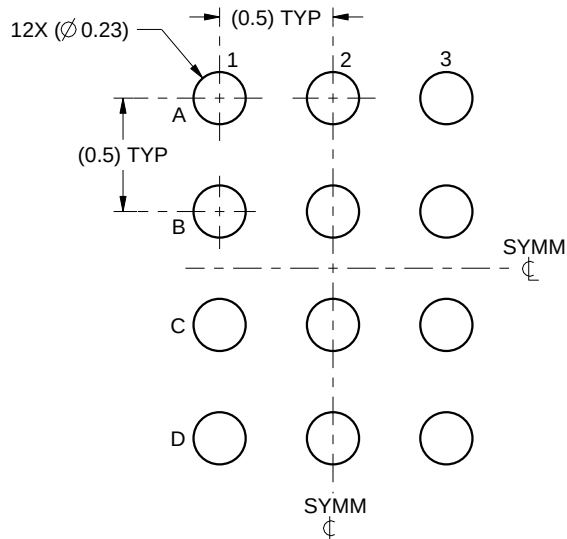
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. NanoFree™ package configuration.

EXAMPLE BOARD LAYOUT

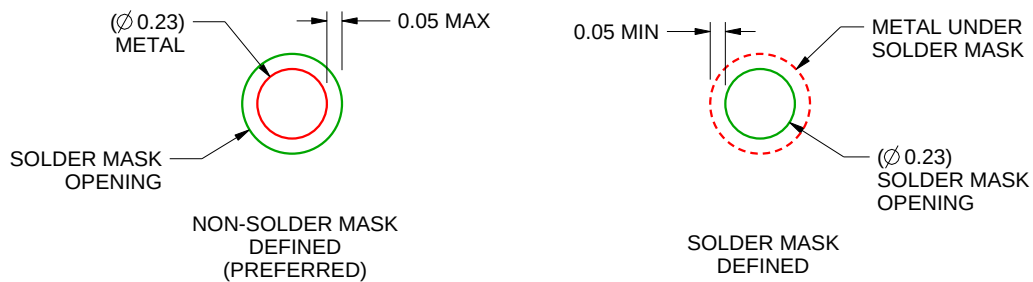
YPH0012

DSBGA - 0.4 mm max height

DIE SIZE BALL GRID ARRAY



LAND PATTERN EXAMPLE
SCALE:30X

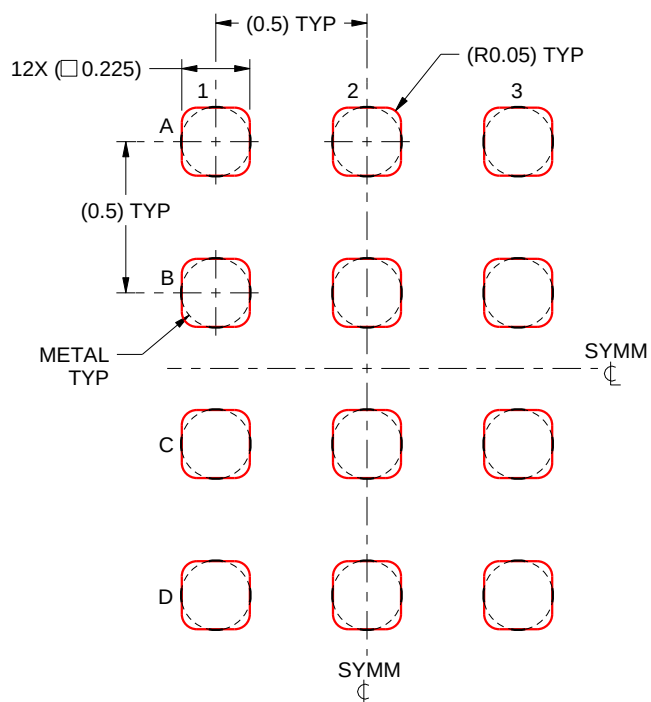


SOLDER MASK DETAILS
NOT TO SCALE

4222640/A 12/2015

NOTES: (continued)

- Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For more information, see Texas Instruments literature number SNVA009 (www.ti.com/lit/snva009).



SOLDER PASTE EXAMPLE
 BASED ON 0.1 mm THICK STENCIL
 SCALE:40X

4222640/A 12/2015

NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.

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